

TECHNICAL DATA
DATA SHEET 783, REV. B

HERMETIC POWER SCHOTTKY RECTIFIER

DESCRIPTION: 100 VOLT, 30 AMP, POWER SCHOTTKY RECTIFIER IN A SHD-1/1B PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ $T_C = 25\text{ }^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED.

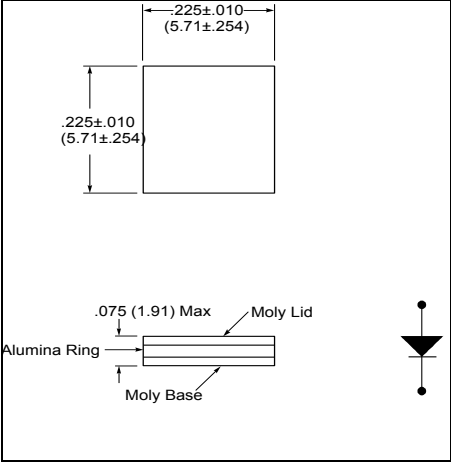
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	100	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_C=100\text{ }^\circ\text{C}$)	I_O	15	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT ($t=8.3\text{ms}$, Sine)	I_{FSM}	280	Amps
MAXIMUM JUNCTION CAPACITANCE ($V_r=5\text{V}$)	C_T	500	pF
MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode)	$R_{\theta JC}$	1.7	$^\circ\text{C/W}$
MAXIMUM OPERATING TEMPERATURE RANGE	T_{op}	-65 to + 175	$^\circ\text{C}$
MAXIMUM STORAGE TEMPERATURE RANGE	T_{stg}	-65 to + 175	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS

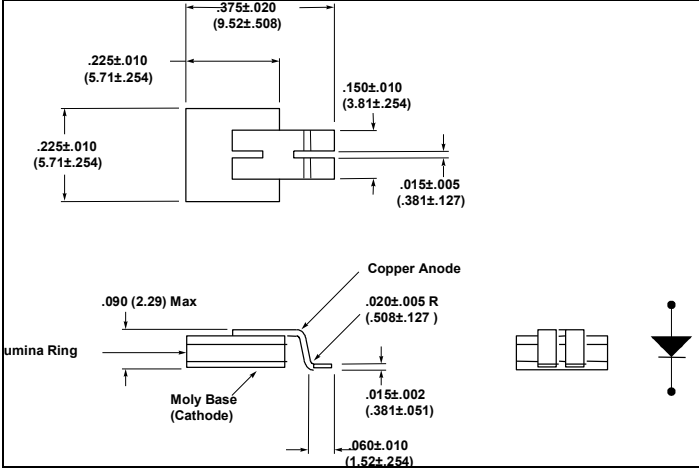
CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed ($I_f = 15\text{ Amps}$) $T_J = 25\text{ }^\circ\text{C}$ $T_J = 125\text{ }^\circ\text{C}$	V_f	0.86 0.67	Volts
MAXIMUM REVERSE CURRENT (I_r @ 100V PIV) $T_J = 25\text{ }^\circ\text{C}$ $T_J = 125\text{ }^\circ\text{C}$	I_r	0.55 12	mA

SENSITRON
DATA SHEET 783, REV. B

MECHANICAL DIMENSIONS: In Inches / mm



SHD-1



SHD-1B

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